UTC UNISONIC TECHNOLOGIES CO., LTD

UK2996 MOSFET

600V SILICON N-CHANNEL POWER MOSFET

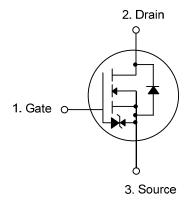
DESCRIPTION

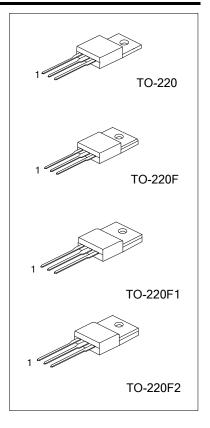
The UK2996 is an N-channel enhancement mode field-effect power transistor. Intended for use in high voltage, high speed switching applications in power supplies, DC-DC converter, relay drive and PWM motor drive controls.

FEATURES

- * Fast Switching Times
- * Improved Inductive Ruggedness
- * High Forward Transfer Admittance
- * Low on Resistance
- * Low Leakage Current
- * Lower Input Capacitance

SYMBOL

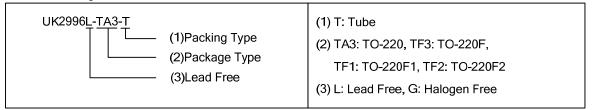




ORDERING INFORMATION

Ordering Number		Doolsono	Pin Assignment			Doolsing	
Lead Free	Halogen Free	Package	1	2	3	Packing	
UK2996L-TA3-T	UK2996G-TA3-T	TO-220	G	D	S	Tube	
UK2996L-TF1-T	UK2996G-TF1-T	TO-220F1	G	D	S	Tube	
UK2996L-TF2-T	UK2996G-TF2-T	TO-220F2	G	D	S	Tube	
UK2996L-TF3-T	UK2996G-TF3-T	TO-220F	G	D	S	Tube	

Note: Pin Assignment: G: Gate D: Drain S: Source



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ABSOLUTE MAXIMUM RATING

PARAMETER		SYMBOL	RATINGS	UNIT
Drain to Source Voltage		V_{DSS}	600	V
Continuous Drain Current		I _D	10	Α
Pulsed Drain Current		I _{DM}	30	Α
Drain to Gate Voltage (R_{GS} = 20 k Ω)		V_{DGR}	600	V
Gate to Source Voltage		V_{GSS}	±30	V
Avalanche Current		I _{AR}	10	Α
Single Pulsed Avalanche energy (Note 2)		E _{AS}	252	mJ
Repetitive Avalanche Energy (Note 3)		E _{AR}	4.5	mJ
Power Dissipation (T _C = 25°C)	TO-220		45	
	TO-220F/TO-220F1	P_{D}	36	W
	TO-220F2]	38	
Junction Temperature		TJ	+150	°C
Storage Temperature		T _{STG}	-55 ~ + 150	°C

Note 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

- 2. L = 4.41 mH, I_{AR} = 10 A, V_{DD} = 90 V, R_G = 25 Ω , starting T_J = 25°C.
- 3. Pulse width and frequency is limited by $T_{\rm J}.\,$

■ THERMAL DATA

CHARACTERISTICS		SYMBOL	RATINGS	UNIT
Channel to Ambient		θ_{JA}	62.5	°C / W
Channel to Case	TO-220		2.78	
	TO-220F/TO-220F1	θ_{JC}	3.47	°C / W
	TO-220F2		3.29	

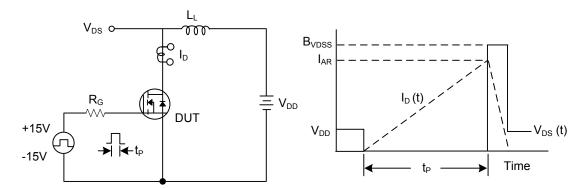
■ ELECTRICAL CHARACTERISTICS (T_A = 25°C)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Gate-Source Breakdown Voltage		BV_{GSS}	$V_{DS} = 0V, I_{G} = \pm 10 \mu A$	±30			V
Drain-Source Breakdown Voltage		BV _{DSS}	$V_{GS} = 0V$, $I_D = 10mA$	600			V
Gate Threshold	Voltage	$V_{GS(TH)}$	$V_{DS} = 10V, I_{D} = 1mA$	2.0		4.0	V
Gate Source Leakage Current		I _{GSS}	$V_{GS} = \pm 25V, V_{DS} = 0V$			±10	μΑ
Drain Source Le	akage Current	I _{DSS}	V _{DS} = 600V, V _{GS} = 0V			100	μΑ
Static Drain-Sor	urce ON Resistance	R _{DS (ON)}	$V_{GS} = 10V, I_D = 5A$		0.74	1. 0	Ω
Forward Transco	onductance	g FS	$V_{DS} = 10V, I_{D} = 5A$	3.4	6.8		S
Input Capacitan	ce	C _{ISS}			1500		
Reverse Transfe	er Capacitance	C _{RSS}	$V_{DS} = 20V, V_{GS} = 0V, f = 1MHz$		13		pF
Output Capacita	ince	Coss			140		
Total Gate Charge		Q_{G}			38		
Gate-Source Charge		Q_{GS}	$I_D = 10A, V_{DD} \approx 400V, V_{GS} = 10V$		21		nC
Gate-Drain Cha	ırge	Q_{GD}			17		
	Turn-on Delay Time	t _{ON}	٩		55		
	Turn-on Rise Time	t _R	R _L =60Ω ≹ I _D =5A Vout		15]
	Turn-off Delay Time	t _{OFF}	Vout		145]
Switching Time	Turn-off Fall Time	t _F	V _{GS} 0V 50Ω V _{DD} ≈ 300V t _P =10 μ s, Duty ≤1%		27		ns

■ SOURCE-DRAIN DIODE CHARACTERISTICS (T_A = 25°C)

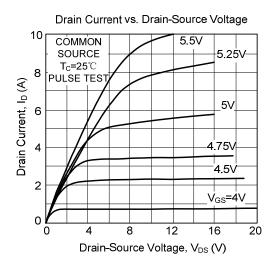
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Diode Forward Voltage	V_{SD}	$V_{GS} = 0V, I_{S} = 10A$			-1.7	V
Continuous Source Current (body diode)	Is	Integral Reverse p-n Junction			10	Α
Pulse Source Current (body diode)	I _{SM}	Diode in the MOSFET Drain Gate Source			30	Α
Reverse Recovery Time	t _{RR}	V _{GS} = 0V, I _S = 10A,		1600		ns
Reverse Recovery Charge	Q_{RR}	$dI_F/dt = 100 A/\mu s$		17		μC

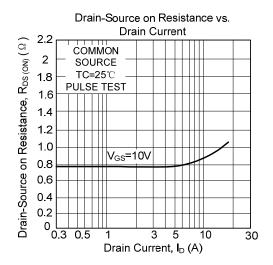
■ TEST CIRCUIT AND WAVE FORM

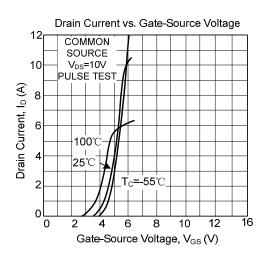


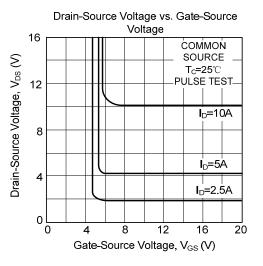
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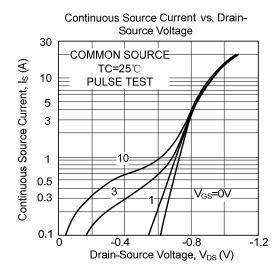
■ TYPICAL CHARACTERISTICS











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